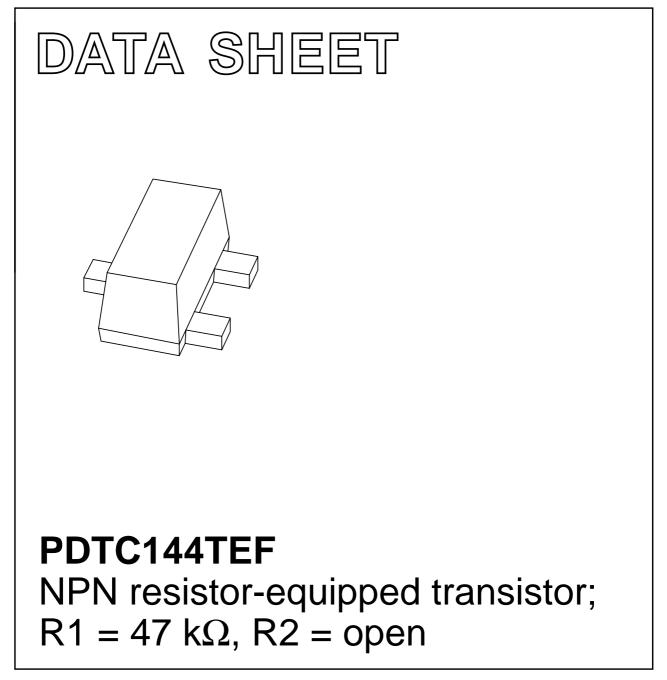
# DISCRETE SEMICONDUCTORS



Product specification

2002 Mar 15



#### **Product specification**

PDTC144TEF

# NPN resistor-equipped transistor; R1 = 47 k $\Omega$ , R2 = open

#### FEATURES

- Built-in bias resistors
- 250 mW total power dissipation
- Very small  $1.6 \times 0.85$  mm thin package
- Flat leads
- Excellent coplanarity
- Improved thermal behaviour
- Reduces number of components and required PCB area.

#### **APPLICATIONS**

- General purpose switching and amplification
- Inverter and interface circuits
- Driver circuits.

#### DESCRIPTION

NPN resistor equipped transistor in a SOT490 (SC-89) plastic package.

#### MARKING

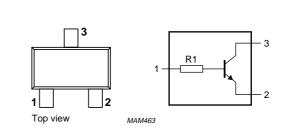
TYPE NUMBER	MARKING CODE		
PDTC144TEF	33		

#### QUICK REFERENCE DATA

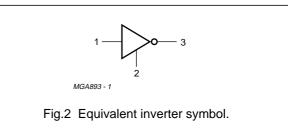
SYMBOL	PARAMETER	MAX.	UNIT	
V <sub>CEO</sub>	collector-emitter voltage	50	V	
I <sub>O</sub>	output current (DC)	100	mA	
R1	bias resistor	47	kΩ	
R2	open	_	_	

#### PINNING

PIN	DESCRIPTION	
1	base/input	
2	emitter/ground (+)	
3	collector/output	



#### Fig.1 Simplified outline (SOT490) and symbol.



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#### LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>CBO</sub>	collector-base voltage	open emitter	-	50	V
V <sub>CEO</sub>	collector-emitter voltage	open base	-	50	V
$V_{\text{EBO}}$	emitter-base voltage	open collector	-	10	V
I <sub>O</sub>	output current (DC)		_	100	mA
I <sub>CM</sub>	peak collector current		-	100	mA
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$ ; note 1	-	250	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
Т <sub>ј</sub>	junction temperature		-	150	°C
T <sub>amb</sub>	operating ambient temperature		-65	+150	°C

#### Note

1. For mounting conditions, see "Thermal considerations and footprint design for SOT490 in the SC18 Data Handbook".

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT	
R <sub>th j-a</sub>	thermal resistance from junction to ambient	in free air; note 1	500	K/W	

#### Note

1. For mounting conditions, see "Thermal considerations and footprint design for SOT490 in the SC18 Data Handbook".

#### CHARACTERISTICS

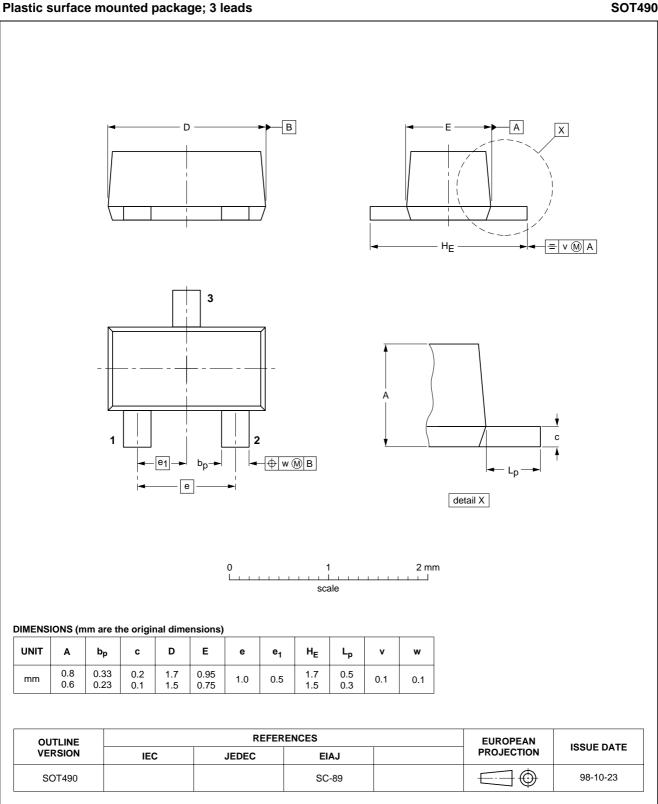
 $T_{amb}$  = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I <sub>CBO</sub>	collector-base cut-off current	$V_{CB} = 50 \text{ V}; \text{ I}_{E} = 0$	-	-	100	nA
I <sub>CEO</sub>	collector-emitter cut-off current	$V_{CE} = 30 \text{ V}; \text{ I}_{B} = 0$	-	-	1	μA
		$V_{CE} = 30 \text{ V}; \text{ I}_{B} = 0; \text{ T}_{j} = 150 ^{\circ}\text{C}$	-	-	50	μA
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; \text{ I}_{C} = 0$	-	-	100	nA
h <sub>FE</sub>	DC current gain	V <sub>CE</sub> = 5 V; I <sub>C</sub> = 1 mA	100	-	-	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_{\rm C} = 10 \text{ mA}; I_{\rm B} = 0.5 \text{ mA}$	-	-	150	mV
R1	input resistor		33	47	61	kΩ
C <sub>c</sub>	collector capacitance	$I_{E} = i_{e} = 0; V_{CB} = 10 V;$ f = 1 MHz	-	-	2.5	pF

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#### PACKAGE OUTLINE



### PDTC144TEF

#### DATA SHEET STATUS

DATA SHEET STATUS <sup>(1)</sup>	PRODUCT STATUS <sup>(2)</sup>	DEFINITIONS
Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
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- 2. The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.

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